



preliminary

Schottky Diode

$$V_{RRM} = 45\text{ V}$$

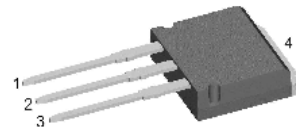
$$I_{FAV} = 15\text{ A}$$

$$V_F = 0.55\text{ V}$$

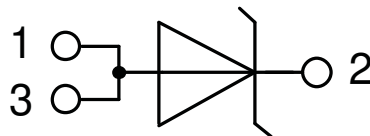
High Performance Schottky Diode
Low Loss and Soft Recovery
Single Diode

Part number

DSB15IM45IB



Backside: cathode



Features / Advantages:

- Very low V_f
- Extremely low switching losses
- Low I_{rm} values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-262 (I2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.

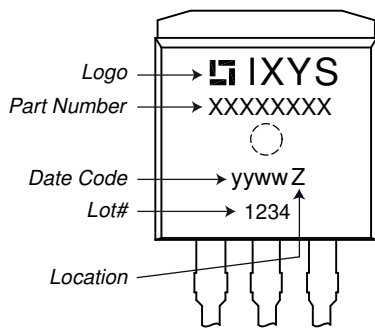


Schottky				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RSM}	max. non-repetitive reverse blocking voltage					45	V
V_{RRM}	max. repetitive reverse blocking voltage					45	V
I_R	reverse current, drain current	$V_R = 45\text{ V}$	$T_{VJ} = 25^\circ\text{C}$			5	mA
		$V_R = 45\text{ V}$	$T_{VJ} = 100^\circ\text{C}$			50	mA
V_F	forward voltage drop	$I_F = 15\text{ A}$	$T_{VJ} = 25^\circ\text{C}$			0.59	V
		$I_F = 30\text{ A}$				0.83	V
		$I_F = 15\text{ A}$	$T_{VJ} = 125^\circ\text{C}$			0.55	V
		$I_F = 30\text{ A}$				0.80	V
I_{FAV}	average forward current	$T_C = 130^\circ\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 150^\circ\text{C}$			15	A
V_{F0}	threshold voltage	} for power loss calculation only				0.31	V
r_F	slope resistance					15.5	mΩ
R_{thJC}	thermal resistance junction to case					1.75	K/W
R_{thCH}	thermal resistance case to heatsink				0.5		K/W
P_{tot}	total power dissipation			$T_C = 25^\circ\text{C}$		70	W
I_{FSM}	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$		$T_{VJ} = 45^\circ\text{C}$		340	A
C_J	junction capacitance	$V_R = 5\text{ V}$	$f = 1\text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		497	pF



Package TO-262 (I2Pak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			35	A
T_{VJ}	virtual junction temperature		-55		150	°C
T_{op}	operation temperature		-55		125	°C
T_{stg}	storage temperature		-55		150	°C
Weight				1.5		g
F_C	mounting force with clip		20		60	N

Product Marking



Part description

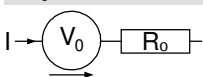
- D = Diode
- S = Schottky Diode
- B = ultra low VF
- 15 = Current Rating [A]
- IM = Single Diode
- 45 = Reverse Voltage [V]
- IB = TO-262 (I2Pak) (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSB15IM45IB	DSB15IM45IB	Tube	50	502322

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 150^{\circ}C$

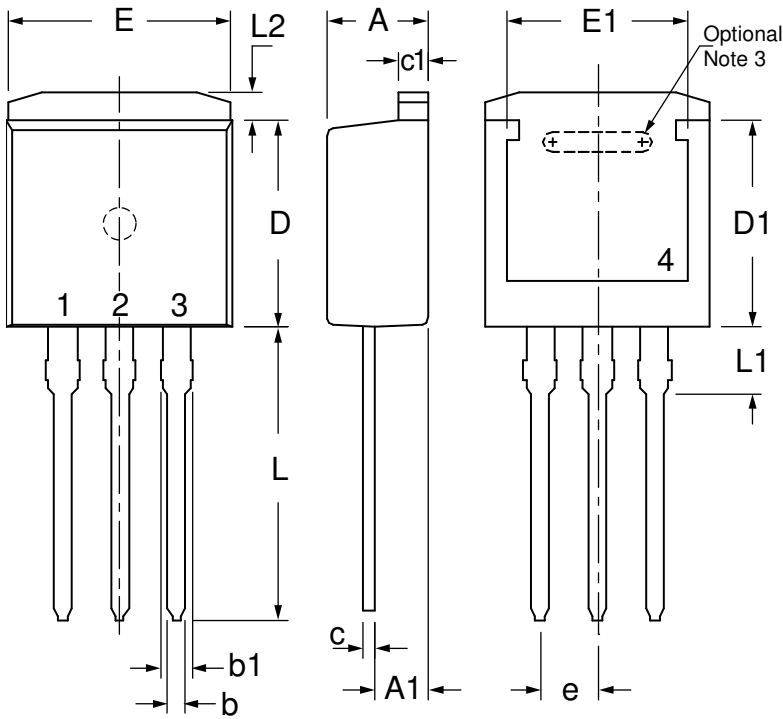


Schottky

$V_{0\ max}$	threshold voltage	0.31	V
$R_{0\ max}$	slope resistance *	12.4	mΩ



Outlines TO-262 (I2Pak)



SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.160	.190	4.06	4.83
A1	.080	.110	2.03	2.79
b	.025	.035	0.64	0.88
b1	.025	.039	1.14	1.40
c	.018	.025	0.46	0.64
c1	.045	.055	1.14	1.40
D	.340	.380	8.64	9.65
D1	.270	.290	6.86	7.37
E	.380	.405	9.65	10.29
E1	.245	.320	6.22	8.13
e	.100 BSC		2.54 BSC	
L	.500	.560	12.70	14.22
L1	.100	.125	2.54	3.18
L2	.040	.055	1.02	1.40

NOTE:

1. This drawing will meet all dimensions requirement of JEDEC outline TO-262 AA.
2. All metal surface are matte pure tin plated except trimmed area.
3. Inter locking slot depends upon frame type.

